

# **78 Series Regulators**

# 1A Output 78 series Regulators 500mA Output 78 series Regulators

BA78 Series, BA78 Series

No.12019ECT01

RoHS

#### Description

BA78 , BA78 series are three-terminal regulators available with several fixed output voltages. It supplies the stable fixes voltage from unstable direct input voltage. The useful output voltage lineup is 5V, 6V, 7V, 8V, 9V, 10V, 12V, 15V, 18V, 20V, 24V with 0.5A / 1A current ability. They have nearly same electric characteristics as competitor products and cover a wide range of application.

#### Features

- 1) Built-in over-current protection circuit and thermal shutdown circuit
- 2) High ripple rejection
- Available TO220CP-3, TO252-3 package to a wide range application 3)
- 4) Compatible replacement to competitor products
- 5) Various voltage lineup (5V, 6V, 7V, 8V, 9V, 10V, 12V, 15V, 18V, 20V, 24V)

#### Applications

Fixed voltage power supply for TV, Audio components, etc

#### Line up

■1A BA78□□Series

Part Number	5V	6V	7V	8V	9V	10V	12V	15V	18V	20V	24V	Package
BA78□□CP	0	0	0	0	0	0	0	0	0	0	0	TO220CP-3
BA78□□FP	0	0	0	0	0	0	0	0	0	0	0	TO252-3

#### ■0.5A BA78M□□Series

Part Number	5V	6V	7V	8V	9V	10V	12V	15V	18V	20V	24V	Package
BA78M□□CP	0	0	0	0	0	0	0	0	0	0	0	TO220CP-3
BA78M□□FP	0	0	0	0	0	0	0	0	0	0	0	TO252-3

#### Output Voltage and Marking

Part Number : BA78 b

а

Part Number : BA78M b а

Symbol	assignment of output voltage					Symbol	assignment of output voltage				
		Output voltage(V)		Output voltage(V)				Output voltage(V)		Output voltage(V)	
	05	5.0V typ.	12	12V typ.			05	5.0V typ.	12	12V typ.	
	06	6.0V typ.	15	15V typ.			06	6.0V typ.	15	15V typ.	
а	07	7.0V typ.	18	18V typ.		а	07	7.0V typ.	18	18V typ.	
	08	8.0V typ.		20V typ.			08	8.0V typ.	20	20V typ.	
	09	9.0V typ.	24	24V typ.			09	9.0V typ.	24	24V typ.	
	10	10 10.0V typ.					10	10.0V typ.			
	Package						Package				
Ŀ		CP : TO220C	P-3			b	CP : TO220CP-3				
b		FP : TO252-3					FP : TO252-3				

# ●Absolute Maximum Rating (Ta=25°C)

Para	meter	Symbol	Limits	Unit					
Power supply voltage		Vin	35	V					
Power Dissipation 1	TO220CP-3	Pd1	2 *1	W					
Power Dissipation 1	TO252-3	Fui	1 *1	vv					
Dower Dissinction 2	TO220CP-3	Pd2	22 <sup>*2</sup>	W					
Power Dissipation 2	TO252-3	Puz	10 *2	vv					
Output Current	BA78	lo	1 <sup>*3</sup>	^					
Output Current	BA78□□M	10	0.5 <sup>*3</sup>	A					
Operating Temperatur	re Range	Topr	-40~+85	°C					
Storage Temperature	Range	Tstg	-55~+150	°C					
Operating Junction Te	emperature Range	Tj	-40~+150	°C					

\*1 Derating in done 16mW/°C(TO220CP-3), 8mW/°C(TO252-3) for temperatures above Ta=25°C

\*2 Derating in done 176mW°C(TO220CP-3), 80mW/°C(TO252-3) for temperatures above Ta=25°C, Mounted on infinity Alminium heat sink.

\*3 Pd,ASO and Tjmax(150°C) should not be exceeded.

### ●Operating Conditions(Ta=25°C, Pd should not be exceeded)

#### BA78 CP/FP Parameter Symbol Min. Max. Unit. 25 BA7805 7.5 BA7806 8.5 21 BA7807 9.5 22 BA7808 10.5 23 BA7809 11.5 26 Input BA7810 Vin 12.5 25 V Voltage BA7812 14.5 27 BA7815 17.5 30 21 33 BA7818 BA7820 23 33 BA7824 27 33 **Output Current** lo -1 А

BA78M□	□CP/FP				
Par	ameter	Symbol	Min.	Max.	Unit.
	BA78M05		7.5	25	
	BA78M06		8.5	21	
	BA78M07		9.5	22	
	BA78M08		10.5	23	
Innut	BA78M09		11.5	26	
Input Voltage	BA78M10	Vin	12.5	25	V
vollage	BA78M12		14.5	27	
	BA78M15		17.5	30	
	BA78M18		21	33	
	BA78M20		23	33	
	BA78M24		27	33	
Output C	urrent	lo	-	0.5	А

#### ●Electrical Characteristics BA78M□□CP/FP

(Ta=25°C, Vin=10V(05), 11V(06), 13V(07), 14V(08), 15V(09), 16V(10), 19V(12), 23V(15), 27V(18), 29V(20), 33V(24), Io=350mA unless otherwise specified)

Parameter	Symbol	Туре	Min	Limit Typ	Max	Unit	Condition	
	1	05	4.8	5.0	5.2			
		06	5.75	6.0	6.25			
		07	6.7	7.0	7.3			
		08	7.7	8.0	8.3			
		09	8.6	9.0	9.4			
Output Voltage 1	Vo1	10	9.6	10.0	10.4	V	Io=350mA	
		12	11.5	12.0	12.5			
		15	14.4	15.0	15.6			
		18	17.3	18.0	18.7			
		20 24	19.2 23.0	20.0 24.0	20.8 25.0			
		05	4.75	24.0	5.25		Vin=7.5~20V, Io=5mA~350mA	
		06	5.7	-	6.3		Vin=8.5~21V, Io=5mA~350mA	
		07	6.65	-	7.35		Vin=9.5~22V, Io=5mA~350mA	
		08	7.6	-	8.4		Vin=10.5~23V, Io=5mA~350mA	
		09	8.55	-	9.45		Vin=11.5~24V, Io=5mA~350mA	
Output Voltage 2	Vo2	10	9.5	-	10.5	V	Vin=12.5~25V, Io=5mA~350mA	
		12	11.4	-	12.6		Vin=15~27V, Io=5mA~350mA	
		15	14.25	-	15.75		Vin=17.5~30V, Io=5mA~350mA	
		18	17.1	-	18.9		Vin=21~33V, Io=5mA~350mA	
		20	19.0	-	21.0		Vin=23~33V, Io=5mA~350mA	
		24	22.8	-	25.2		Vin=27~33V, Io=5mA~350mA	
		05	-	3	100		Vin=7~25V, lo=200mA	
		06	-	3	100		Vin=8~25V, lo=200mA	
		07 08	-	4	100 100		Vin=9~25V, Io=200mA Vin=10.5~25V, Io=200mA	
	Reg.I1	08	-	4	100		Vin=10.5~25V, 10=200mA	
Line Regulation 1		10	-	5	100	mV	Vin=12.5~28V, lo=200mA	
		12	_	5	100	IIIV	Vin=14.5~30V, lo=200mA	
		15	-	6	100		Vin=17.5~30V, lo=200mA	
		18	-	7	100		Vin=21~33V, Io=200mA	
		20	-	8	100		Vin=23~33V, Io=200mA	
		24	-	10	100		Vin=27~33V, Io=200mA	
		05	-	1	50		Vin=8~12V, Io=200mA	
		06	-	1	50		Vin=9~25V, Io=200mA	
		07	-	1	50		Vin=10~25V, Io=200mA	
		08	-	1	50		Vin=11~25V, Io=200mA	
		09	-	2	50		Vin=12~25V, Io=200mA	
Line Regulation 2	Reg.I2	10	-	2	50	mV	Vin=14~26V, Io=200mA	
		12	-	3	50		Vin=16~30V, Io=200mA	
		15	-	3	50		Vin=20~30V, lo=200mA	
		18 20	-	3	50 50		Vin=24~33V, Io=200mA Vin=24~33V, Io=200mA	
		20	-	5	50		Vin=24~33V, Io=200mA	
		05	62	78	-			
		06	60	74	-			
		07	57	71	-			
		08	56	69	-			
		09	56	67	-			
Ripple Rejection	R.R.	10	56	66	-	dB	ein=1Vrms, f=120Hz, Io=100mA	
		12	55	63	-			
		15	54	60	-			
		18	53	58	-			
		20	53	58	-			
		24	50	55	-			
Temperature		05	-	-1.0	-			
Coefficient of	Тсvo	06/07/08/09/10/12	-	-0.5	-	mV/°C	lo=5mA, Tj=0∼125°C	
Output Voltage	-	15/18	-	-0.6	-			
	lo-p	20/24 common	-	-0.7 875	-	mA	Tj=25°C	
Peak Output Current					-			

### ●Electrical Characteristics BA78M□□CP/FP

 $(Ta=25^{\circ}C, Vin=10V(05), 11V(06), 13V(07), 14V(08), 15V(09), 16V(10), 19V(12), 23V(15), 27V(18), 29V(20), 33V(24), Io=350 \text{mA} \text{ unless otherwise specified})$ 

Deversion		<b>T</b>		Limit		11-2	A unless otherwise specified)
Parameter	Symbol	Туре	Min	Тур	Max	Unit	Condition
		05	-	20	100		
		06	-	20	120		
		07	-	20	140		
		08	-	20	160		
		09	-	20	180		
Load Regulation 1	Reg.L1	10	-	20	200	mV	Io=5mA~500mA
		12	-	20	240		
		15	-	20	300		
		18	-	20	360		
		20	-	20	400		
		24	-	20	480		
		05	-	10	50		
		06	-	10	60		
		07	-	10	70		
		08	-	10	80		
		09	-	10	90		
Load Regulation 2	Reg.L2	10	-	10	100	mV	lo=5mA~200mA
		12	-	10	120		
		15	-	10	150		
		18	-	10	180		
		20	-	10	200		
		24	-	10	240		
		05	-	40	-		
		06	-	60	-		
		07	-	70	-		
		08	-	80	-		
O de la Nala a		09	-	90	-		
Output Noise	Vn	10	-	100	-	μV	f=10Hz~100kHz
Voltage		12	-	110	-	-	
		15	-	130	-		
		18	-	140	-		
		20	-	150	-		
		24	-	170	-		
Bias Current	lb	common	-	4.5	6.0	mA	lo=0mA
Bias Current Change1	1	common	-	-	0.5	mA	lo=5mA~350mA
	lb1	CONTINUE					
	lb1	05	-	-	0.8		Vin:8~25V, lo=200mA
	lb1		-	-	0.8 0.8		
	lb1	05					Vin:8~25V, Io=200mA
	lb1	05 06 07	-	-	0.8 0.8		Vin:8~25V, Io=200mA Vin:9~25V, Io=200mA Vin:10~25V, Io=200mA
	lb1	05 06	-	-	0.8		Vin:8~25V, Io=200mA Vin:9~25V, Io=200mA
	lb1	05 06 07 08	-	- - -	0.8 0.8 0.8	mA	Vin:8~25V, Io=200mA Vin:9~25V, Io=200mA Vin:10~25V, Io=200mA Vin:10.5~25V, Io=200mA
		05 06 07 08 09	- - - -	- - - -	0.8 0.8 0.8 0.8	mA	Vin:8~25V, Io=200mA Vin:9~25V, Io=200mA Vin:10~25V, Io=200mA Vin:10.5~25V, Io=200mA Vin:12~25V, Io=200mA
Bias Current Change 2		05 06 07 08 09 10 12	- - - -	- - - -	0.8 0.8 0.8 0.8 0.8 0.8	mA	Vin:8~25V, Io=200mA Vin:9~25V, Io=200mA Vin:10~25V, Io=200mA Vin:10.5~25V, Io=200mA Vin:12~25V, Io=200mA Vin:13~25V, Io=200mA Vin:14.5~30V, Io=200mA
		05 06 07 08 09 10	- - - - -	- - - - -	0.8 0.8 0.8 0.8 0.8	mA	Vin:8~25V, Io=200mA Vin:9~25V, Io=200mA Vin:10~25V, Io=200mA Vin:10.5~25V, Io=200mA Vin:12~25V, Io=200mA Vin:13~25V, Io=200mA
		05 06 07 08 09 10 12 15 18	- - - - - - -	- - - - - - -	0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8	mA	Vin:8~25V, Io=200mA Vin:9~25V, Io=200mA Vin:10~25V, Io=200mA Vin:10.5~25V, Io=200mA Vin:12~25V, Io=200mA Vin:13~25V, Io=200mA Vin:14.5~30V, Io=200mA Vin:17.5~30V, Io=200mA Vin:21~33V, Io=200mA
		05 06 07 08 09 10 12 15 18 20	-	- - - - - - - - -	0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8	mA	Vin:8~25V, Io=200mA Vin:9~25V, Io=200mA Vin:10~25V, Io=200mA Vin:10.5~25V, Io=200mA Vin:12~25V, Io=200mA Vin:13~25V, Io=200mA Vin:14.5~30V, Io=200mA Vin:21~33V, Io=200mA Vin:23~33V, Io=200mA
Bias Current Change 2	lb2	05 06 07 08 09 10 12 15 15 18 20 24	- - - - - - - - - - -	- - - - - - - - - - -	0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8		Vin:8~25V, Io=200mA Vin:9~25V, Io=200mA Vin:10~25V, Io=200mA Vin:10.5~25V, Io=200mA Vin:12~25V, Io=200mA Vin:13~25V, Io=200mA Vin:14.5~30V, Io=200mA Vin:21~33V, Io=200mA Vin:23~33V, Io=200mA Vin:27~33V, Io=200mA
Bias Current Change 2 Short-Circuit		05 06 07 08 09 10 12 15 15 18 20 24 05/06/07/08	- - - - - - - - - - - - - -	- - - - - - - - - - - - - - - - - -	0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8	mA	Vin:8~25V, lo=200mA Vin:9~25V, lo=200mA Vin:10~25V, lo=200mA Vin:10.5~25V, lo=200mA Vin:12~25V, lo=200mA Vin:13~25V, lo=200mA Vin:14.5~30V, lo=200mA Vin:21~33V, lo=200mA Vin:23~33V, lo=200mA Vin:27~33V, lo=200mA Vin:27~33V, lo=200mA Vin:27~33V, lo=200mA
Bias Current Change 2 Short-Circuit	lb2	05 06 07 08 09 10 12 15 15 18 20 24	- - - - - - - - - - - - - - - - -	- - - - - - - - - -	0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8		Vin:8~25V, Io=200mA Vin:9~25V, Io=200mA Vin:10~25V, Io=200mA Vin:10.5~25V, Io=200mA Vin:12~25V, Io=200mA Vin:13~25V, Io=200mA Vin:14.5~30V, Io=200mA Vin:21~33V, Io=200mA Vin:23~33V, Io=200mA Vin:27~33V, Io=200mA
Bias Current Change 2 Short-Circuit	lb2	05 06 07 08 09 10 12 15 18 20 24 05/06/07/08 09/10/12/15/18/20/24 05	- - - - - - - - - - - - - - - - - - -	- - - - - - - - - - - - - - - - - - -	0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8		Vin:8~25V, lo=200mA Vin:9~25V, lo=200mA Vin:10~25V, lo=200mA Vin:10.5~25V, lo=200mA Vin:12~25V, lo=200mA Vin:13~25V, lo=200mA Vin:14.5~30V, lo=200mA Vin:21~33V, lo=200mA Vin:23~33V, lo=200mA Vin:27~33V, lo=200mA Vin:27~33V, lo=200mA Vin:27~33V, lo=200mA
Bias Current Change 2 Short-Circuit	lb2	05 06 07 08 09 10 12 15 18 20 24 05/06/07/08 09/10/12/15/18/20/24 05 06	- - - - - - - - - - - - - - - - - - -	- - - - - - - - - - - - - - - - - - -	0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8		Vin:8~25V, lo=200mA Vin:9~25V, lo=200mA Vin:10~25V, lo=200mA Vin:10.5~25V, lo=200mA Vin:12~25V, lo=200mA Vin:13~25V, lo=200mA Vin:14.5~30V, lo=200mA Vin:21~33V, lo=200mA Vin:23~33V, lo=200mA Vin:27~33V, lo=200mA Vin:27~33V, lo=200mA Vin:27~33V, lo=200mA
Bias Current Change 2 Short-Circuit	lb2	05 06 07 08 09 10 12 15 18 20 24 05/06/07/08 09/10/12/15/18/20/24 05 06 07	- - - - - - - - - - - - - - - - - - -	- - - - - - - - - - - - - - - - - - -	0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8		Vin:8~25V, lo=200mA Vin:9~25V, lo=200mA Vin:10~25V, lo=200mA Vin:10.5~25V, lo=200mA Vin:12~25V, lo=200mA Vin:13~25V, lo=200mA Vin:14.5~30V, lo=200mA Vin:21~33V, lo=200mA Vin:23~33V, lo=200mA Vin:27~33V, lo=200mA Vin:27~33V, lo=200mA Vin:27~33V, lo=200mA
Bias Current Change 2 Short-Circuit	lb2	05 06 07 08 09 10 12 15 18 20 24 05/06/07/08 09/10/12/15/18/20/24 05 06 07 08	- - - - - - - - - - - - - - - - - - -	- - - - - - - - - - - - - - - - - - -	0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8		Vin:8~25V, Io=200mA Vin:9~25V, Io=200mA Vin:10~25V, Io=200mA Vin:10.5~25V, Io=200mA Vin:12~25V, Io=200mA Vin:13~25V, Io=200mA Vin:14.5~30V, Io=200mA Vin:21~33V, Io=200mA Vin:23~33V, Io=200mA Vin:27~33V, Io=200mA Vin:27~33V, Io=200mA Vin:27~33V, Io=200mA
Bias Current Change 2 Short-Circuit Output Current	lb2 los	05 06 07 08 09 10 12 15 18 20 24 05/06/07/08 09/10/12/15/18/20/24 05 06 07 08 09		- - - - - - - - - - - - - - - - - - -	0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8	A	Vin:8~25V, lo=200mA Vin:9~25V, lo=200mA Vin:10~25V, lo=200mA Vin:10.5~25V, lo=200mA Vin:12~25V, lo=200mA Vin:13~25V, lo=200mA Vin:14.5~30V, lo=200mA Vin:21~33V, lo=200mA Vin:23~33V, lo=200mA Vin:27~33V, lo=200mA Vin:27~33V, lo=200mA Vin:25V Vin=30V
Bias Current Change 2 Short-Circuit Output Current	lb2	05 06 07 08 09 10 12 15 18 20 24 05/06/07/08 09/10/12/15/18/20/24 05 06 07 06 07 08 09 10	- - - - - - - - - - - - - - - - - - -	- - - - - - - - - - - - - - - - - - -	0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8		Vin:8~25V, lo=200mA Vin:9~25V, lo=200mA Vin:10~25V, lo=200mA Vin:10.5~25V, lo=200mA Vin:12~25V, lo=200mA Vin:13~25V, lo=200mA Vin:14.5~30V, lo=200mA Vin:21~33V, lo=200mA Vin:23~33V, lo=200mA Vin:27~33V, lo=200mA Vin:27~33V, lo=200mA Vin:27~33V, lo=200mA
Bias Current Change 2 Short-Circuit Output Current	lb2 los	05 06 07 08 09 10 12 15 18 20 24 05/06/07/08 09/10/12/15/18/20/24 05 06 07 06 07 08 09 10 12	- - - - - - - - - - - - - - - - - - -	- - - - - - - - - - - - - - - - - - -	0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8	A	Vin:8~25V, lo=200mA Vin:9~25V, lo=200mA Vin:10~25V, lo=200mA Vin:10~25V, lo=200mA Vin:12~25V, lo=200mA Vin:13~25V, lo=200mA Vin:14.5~30V, lo=200mA Vin:21~33V, lo=200mA Vin:23~33V, lo=200mA Vin:27~33V, lo=200mA Vin:27~33V, lo=200mA Vin:25V Vin=30V
	lb2 los	05 06 07 08 09 10 12 15 18 20 24 05/06/07/08 09/10/12/15/18/20/24 05 06 07 06 07 08 09 09 10 12 15		- - - - - - - - - - - - - - - - - - -	0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8	A	Vin:8~25V, lo=200mA Vin:9~25V, lo=200mA Vin:10~25V, lo=200mA Vin:10~25V, lo=200mA Vin:12~25V, lo=200mA Vin:13~25V, lo=200mA Vin:14.5~30V, lo=200mA Vin:21~33V, lo=200mA Vin:23~33V, lo=200mA Vin:27~33V, lo=200mA Vin:27~33V, lo=200mA Vin:25V Vin=30V
Bias Current Change 2 Short-Circuit Output Current	lb2 los	05 06 07 08 09 10 12 15 18 20 24 05/06/07/08 09/10/12/15/18/20/24 05 06 07 06 07 08 09 10 12		- - - - - - - - - - - - - - - - - - -	0.8 0.8 0.8 0.8 0.8 0.8 0.8 0.8	A	Vin:8~25V, lo=200mA Vin:9~25V, lo=200mA Vin:10~25V, lo=200mA Vin:10~25V, lo=200mA Vin:12~25V, lo=200mA Vin:13~25V, lo=200mA Vin:14.5~30V, lo=200mA Vin:21~33V, lo=200mA Vin:23~33V, lo=200mA Vin:27~33V, lo=200mA Vin:27~33V, lo=200mA Vin:25V Vin=30V

### ●Electrical Characteristics BA78□□CP/FP

(Ta=25°C,Vin=10V(05),11V(06),13V(07),14V(08),15V(09),16V(10),19V(12),23V(15),27V(18),29V(20),33V(24),Io=500mA unless otherwise specified)

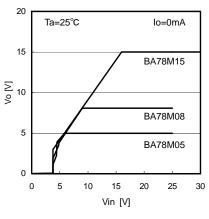
		10(00),130(09),100(10),190		Limit		,	
Parameter	Symbol	Туре	Min	Тур	Max	Unit	Condition
		05	4.8	5.0	5.2		
		06	5.75	6.0	6.25		
		07	6.7	7.0	7.3		
		08	7.7	8.0	8.3		
		09	8.6	9.0	9.4		
Output Voltage 1	Vo1	10	9.6	10.0	10.4	V	lo=500mA
		12	11.5	12.0	12.5		
		15	14.4	15.0	15.6		
		18	17.3	18.0	18.7		
		20	19.2	20.0	20.8		
		24	23.0	24.0	25.0		
		05	4.75	-	5.25		Vin=7.5~20V, Io=5mA~1A
		06	5.7	-	6.3		Vin=8.5~21V, Io=5mA~1A
		07	6.65	-	7.35		Vin=9.5~22V, Io=5mA~1A
		08	7.6	-	8.4		Vin=10.5~23V, lo=5mA~1A
		09	8.55	-	9.45		Vin=11.5~26V, lo=5mA~1A
Output Voltage 2	Vo2	10	9.5	-	10.5	V	Vin=12.5~25V, Io=5mA~1A
		12	11.4	-	12.6		Vin=15~27V, Io=5mA~1A
		15	14.25	-	15.75		Vin=17.5~30V, Io=5mA~1A
		18	17.1	-	18.9		Vin=21~33V, Io=5mA~1A
		20	19.0	-	21.0		Vin=23~33V, Io=5mA~1A
		24	22.8	-	25.2		Vin=27~33V, Io=5mA~1A
Line Regulation 1		05	-	3	100		Vin=7~25V, Io=500mA
		06	-	4	120		Vin=8~25V, Io=500mA
		07	-	5	140		Vin=9~25V, Io=500mA
		08	-	5	160		Vin=10.5~25V, lo=500mA
		09	-	6	180		Vin=11.5~26V, lo=500mA
	Reg.I1	10	-	7	200	mV	Vin=12.5~27V, Io=500mA
		12	-	8	240		Vin=14.5~30V, lo=500mA
		15	-	9	300		Vin=17.5~30V, lo=500mA
		18	-	10	360		Vin=21~33V, Io=500mA
		20	-	12	400		Vin=23~33V, Io=500mA
		24	-	15	480		Vin=27~33V, lo=500mA
		05	-	1	50	_	Vin=8~12V, Io=500mA
		06	-	2	60		Vin=9~13V, Io=500mA
		07	-	2	70		Vin=10~15V, lo=500mA
		08	-	3	80		Vin=11~17V, Io=500mA
Line Deculation 0	Devio	09	-	4	90		Vin=13~19V, lo=500mA
Line Regulation 2	Reg.l2	10	-	4	100	mV	Vin=14~20V, lo=500mA
		12	-	5	120		Vin=16~22V, Io=500mA
		15	-	5	150		Vin=20~26V, lo=500mA
		18	-	5	180		Vin=24~30V, lo=500mA
		20	-	7	200		Vin=26~32V, Io=500mA
		24 05	-	10 78	240		Vin=30~33V, lo=500mA
		05	62 59	78	-		
		06					
		07	57 56	69 65	-		
Pipplo Poinction	R.R.	09	56 55	64 64	-	P	ein=1Vrms, f=120Hz,
Ripple Rejection	к.к.	10 12	55 55	64 63	-	dB	lo=100mA
		12	55 54	63	-		
		15	54 53	62 61			
		20	53	60	-		
		20	53	58			
		05	50		-		
			-	-1.0	-		
Temperature				05		m\//°C	
Temperature Coefficient of	Тсvо	06/07/08/09/10/12	-	-0.5	-	mV/°C	lo=5mA, Tj=0∼125°C
•	Тсvо	06/07/08/09/10/12 15/18	-	-0.6	-	mV/°C	lo=5mA, Tj=0∼125°C
Coefficient of	Тсvо	06/07/08/09/10/12				mV/°C	lo=5mA, Tj=0∼125°C Tj=25°C

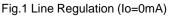
# ●Electrical Characteristics BA78□□CP/FP

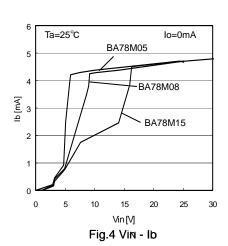
(Ta=25°C,Vin=10V(05),11V(06),13V(07),14V(08),15V(09),16V(10),19V(12),23V(15),27V(18),29V(20),33V(24),Io=500mA unless otherwise specified)

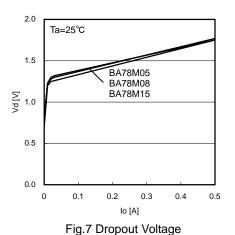
		10(08),150(09),160(10),190(12	,,_0,,(10),21	Limit			
Parameter	Symbol	Туре	Min	Тур	Max	Unit	Condition
		05	-	15	100		
		06	-	16	120		
		07	-	17	140		
		08	-	19	160		
		09	-	20	180		
Load Regulation 1	Reg.L1	10	-	21	200	mV	lo=5mA~1A
Load Regulation 1	Reg.L1	12	-	23	200	IIIV	
		15	-	23	300		
		18	-	30	360		
		20	-	30	400		
		20	-	32	400		
			-				
		05	-	5	50	-	
		06	-	6	60		
		07	-	6	70		
		08	-	7	80		
		09	-	8	90		
Load Regulation 2	Reg.L2	10	-	8	90	mV	lo=250mA~750mA
		12	-	10	100		
		15	-	10	150		
		18	-	12	180		
		20	-	14	200		
		24	-	15	240		
		05	-	40	-		
		06	-	60	-		
		07	-	70	-		
		08	-	80	-		
Output Naisa		09	-	90	-		
Output Noise Voltage	Vn	10	-	100	-	μV	f=10Hz~100kHz
vollage		12	-	110	-		
		15	-	125	-		
		18	-	140	-		
		20	-	150	-		
		24	-	180	-		
Bias Current	lb	common	-	4.5	8.0	mA	lo=0mA
Bias Current Change 1	lb1	common	-	-	0.5	mA	lo=5mA~1A
ÿ		05	-	-	0.8		Vin:8~25V, Io=500mA
		06	-	-	0.8		Vin:8.5~25V, Io=500mA
		07	-	-	0.8		Vin:9.5~25V, Io=500mA
		08	-	-	0.8		Vin:10.5~25V, Io=500mA
		09	-	-	0.8		Vin:11.5~26V, Io=500mA
Bias Current Change 2	lb2	10	-	_	0.8	mA	Vin:12.5~27V, Io=500mA
Sido Curroni Oriange Z	102	12	-	-	0.8	1174	Vin:14.5~30V, Io=500mA
		15	-	_	0.8		Vin:17.5~30V, Io=500mA
		18	-	-	0.8		Vin:21~33V, Io=500mA
		20	-		0.8		Vin:23~33V, Io=500mA
		20	-	-	0.8		Vin:27~33V, I0=500mA
Chart Circuit	-	05/06/07/08			0.0		
Short-Circuit Output Current	los	09/10/12/15/18/20/24	-	0.6	-	A	Vin=25V Vin=30V
Output Current				0.3			VIII=30V
		05	-	9	-		
		06		10	-		
		07		10	-		
		08		10	-		
		09	-	10	-		
Output Resistance	Ro	10	-	11	-	mΩ	f=1kHz
Output Resistance						1	
Output Resistance	RO	12	-	12	-		
Output Resistance	RO	12 15	-	12 14	-		
Output Resistance	RO						
Output Resistance	КО	15	-	14	-		

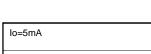
# ●BA78M□□ Characteristics data(Ta=25°C, Vin=10V(05), 14V(08), 23V(15) unless otherwise specified)



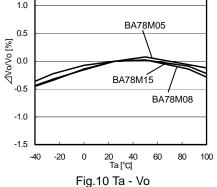








1.5



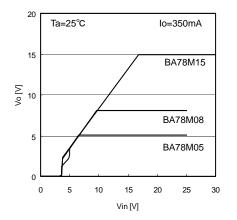
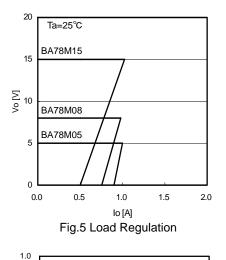
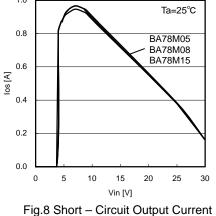
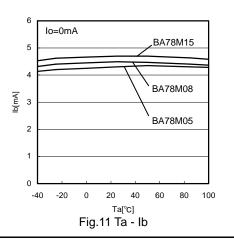


Fig.2 Line Regulation (Io=350mA)







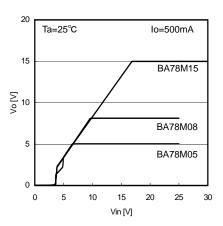
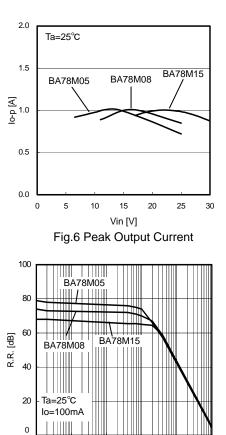


Fig.3 Line Regulation(Io=500mA)



Frequency [Hz] Fig.9 Ripple Rejection Ratio

10K

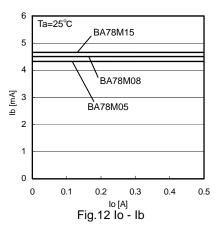
100K

1M

1K

10

100

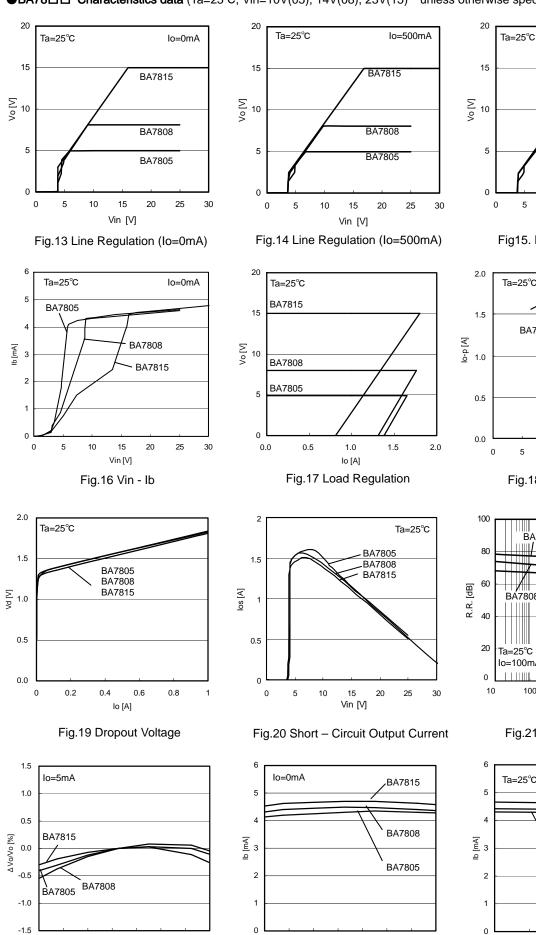


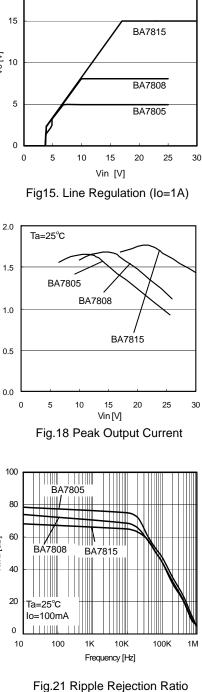
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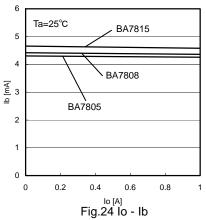


lo=1A

# ●BA78□□ Characteristics data (Ta=25°C, Vin=10V(05), 14V(08), 23V(15) unless otherwise specified)







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0 20

40 60 80 100

Ta [°C]

Fig.22 Ta - Vo

-40 -20



Ta [°C]

Fig.23 Ta - Ib

20

40 60 80

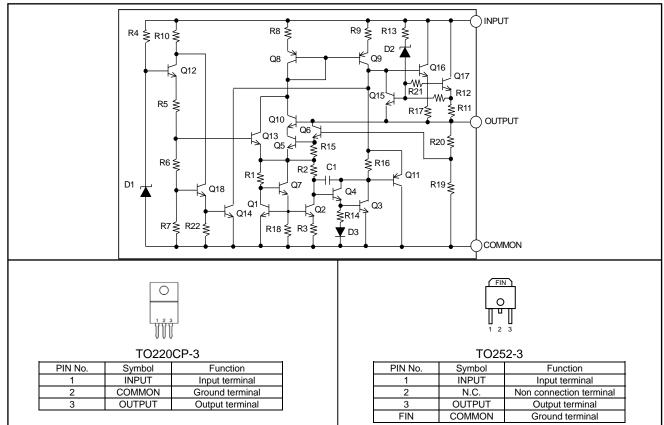
100

-20

0

-40

# Internal Circuit Structural Diagram



Protection Circuit

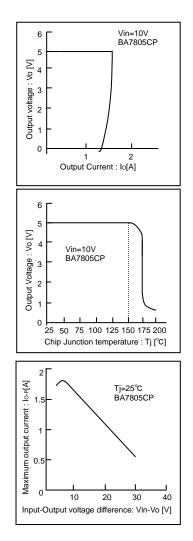
- (1)Over-current protection circuit When the maximum rating current or more is rushed, it controls the current ability and protects the IC from destruction.
- (2) Thermal shutdown circuit When the chip temperature of I

When the chip temperature of IC exceeds the setting temperature, the IC goes OFF, and it controls the IC not to be destroyed by the heat generation. It can be restored by being lowered the chip temperature of IC below the setting temperature.

(3) Safety operation area control circuit

It controls the output current in inverse proportion ratio to voltage difference (input-output).

When voltage difference becomes bigger, the IC will be destroyed in rush current. It protects the IC by controlling the current ability according to the voltage level.



#### Thermal design

Refer to the following thermal derating curves (Fig. 25, 26), when using in the status of Ta=25°C or more.

The characteristic of IC is greatly related to the operating temperature.

When it is used in over maximum junction temperature, the elements inside IC might become weaker and be destroyed. It is recommended to take into consideration thermal of IC.

Note that the temperatures are in the allowed temperature limits and operated within Pd.

It is necessary to operate it at junction temperature Tjmax or less to prevent IC from the thermal destruction.

Please operate IC within permissible loss Pd because the junction temperature Tj might become considerably a high temperature even if ambient temperature Ta is normal temperature (25°C).

Power consumption Pc(W) may be expressed by the equation shown below:

Pc=(Vin-Vo) × Io+ Vin × I b	Vin	: Input Voltage
permissible loss Pd≧Pc	Vo	: Output Voltage
Pd – Vin × Ib	lo	: Output Current
$Io \leq \frac{Pd - Vin \times Ib}{Io}$	lb	: Bias current
Vin – Vo		

Maximum Output current Io<sub>MAX</sub> can be calculated in thermal design.

· Calculation example

Ex.1) Ta=85°C, Vin =7.5V, Vo=5.0V

 $lo \leq \frac{1.04 - 7.5 \times 4.5m}{10}$ 7.5 - 5.0lo≦400mA

Using TO220CP-3 alone θ ja=62.5°C/W→16mW/°C Pd=1.04W at 85°C

Be sure to use this IC within a power dissipation at the range of operating temperature.

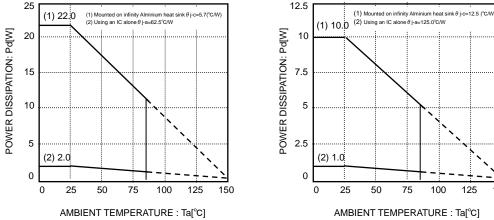


Fig.25 Thermal derating curve (TO220CP-3)

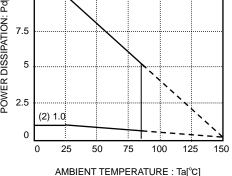


Fig.26 Thermal derating curve (TO252-3)

#### Terminal Setting and Cautions

INPUT

It is recommended that a capacitor (about 0.33uF) be inserted between INPUT and COMMON. The value of capacitor is designed suitable for the actual application.

OUTPUT

It is recommended that a capacitor (about 0.1uF) be inserted between OUTPUT and COMMON. A tantalum capacitor can also be used for this pin because insufficient capacitors may cause oscillation by a temperature change.

#### COMMON

Keep the no voltage drop between Ground level of set board and IC. When there is the voltage difference, setting voltage becomes inaccuracy and unstable. It is recommended to connect by wide, short pattern, and lower the inpedance.

#### Notes for use

(1) Absolute Maximum Ratings

While utmost care is taken to quality control of this product, any application that may exceed some of the absolute maximum ratings including the voltage applied and the operating temperature range may result in breakage. If broken, short-mode or open-mode may not be identified. So if it is expected to encounter with special mode that may exceed the absolute maximum ratings, it is requested to take necessary safety measures physically including insertion of fuses. (2) Ground voltage

Make setting of the potential of the GND terminal so that it will be maintained at the minimum in any operating state.

Furthermore, check to be sure no terminals are at a potential lower than the GND voltage including an actual electric transient. (3) Thermal design

When you do the kind of use which exceeds Pd, It may be happened to deteriorating IC original quality such as decrease of electric current ability with chip temperature rise. Do not exceed the power dissipation (Pd) of the package specification rating under actual operation, and please design enough temperature margins.

(4) Short-circuiting between terminals, and mismounting

When mounting to pc board, care must be taken to avoid mistake in its orientation and alignment. Failure to do so may result in IC breakdown. Short-circuiting due to foreign matters entered between output terminals, or between output and power supply or GND may also cause breakdown.

(5) Operation in Strong electromagnetic field

Be noted that using the IC in the strong electromagnetic radiation can cause operation failures.

(6) Inspection with the IC set to a pc board

If a capacitor must be connected to the pin of lower impedance during inspection with the IC set to a pc board, the capacitor must be discharged after each process to avoid stress to the IC. For electrostatic protection, provide proper grounding to assembling processes with special care taken in handling and storage. When connecting to jigs in the inspection process, be sure to turn OFF the power supply before it is connected and removed.

(7) Input to IC terminals

This is a monolithic IC with  $P^+$  isolation between P-substrate and each element as illustrated below. This P-layer and the N-layer of each element form a P-N junction, and various parasitic element are formed.

If a resistor is joined to a transistor terminal as shown in Fig 28.

OP-N junction works as a parasitic diode if the following relationship is satisfied;

GND>Terminal A (at resistor side), or GND>Terminal B (at transistor side); and

Oif GND>Terminal B (at NPN transistor side),

a parasitic NPN transistor is activated by N-layer of other element adjacent to the above-mentioned parasitic diode. The structure of the IC inevitably forms parasitic elements, the activation of which may cause interference among circuits, and/or malfunctions contributing to breakdown. It is therefore requested to take care not to use the device in such manner that the voltage lower than GND (at P-substrate) may be applied to the input terminal, which may result in activation of parasitic elements.

(8) Ground wiring pattern

If small-signal GND and large-current GND are provided, It will be recommended to separate the large-current GND pattern from the small-signal GND pattern and establish a single ground at the reference point of the set PCB so that resistance to the wiring pattern and voltage fluctuations due to a large current will cause no fluctuations in voltages of the small-signal GND. Pay attention not to cause fluctuations in the GND wiring pattern of external parts as well.

(9) Thermal shutdown circuit

A temperature control circuit is built in the IC to prevent the damage due to overheat. Therefore, the output is turned off when the thermal circuit works and is turned on when the temperature goes down to the specified level.

#### But, built-in the IC a temperature control circuit to protect itself, and avoid the design used the thermal protection.

(10) Over current protection circuit

The over-current protection circuits are built in at output, according to their respective current outputs and prevent the IC from being damaged when the load is short-circuited or over-current. But, these protection circuits are effective for preventing destruction by unexpected accident. When it's in continuous protection circuit moving period don't use please. And for ability, because this chip has minus characteristic, be careful for heat plan.

(11) There is a possibility to damage an internal circuit or the element when Vin and the voltage of each terminal reverse in the application. For instance, Vin is short-circuited to GND etc. with the charge charged to an external capacitor. Please use the capacitor of the output terminal with 1000µF or less. Moreover, the Vin series is recommended to insert the diode of the by-pass the diode of the backflow prevention or between each terminal and Vin.
Pin B

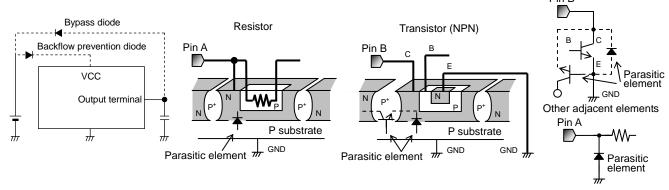
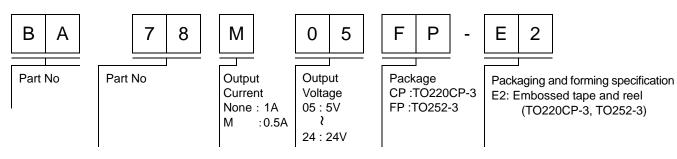


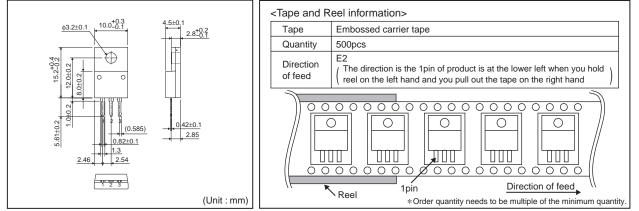
Fig.27 Bypass Diode

Fig.28 Simplified structure of monorisic IC

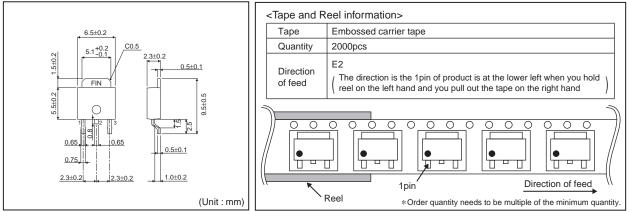
### Ordering part number



# TO220CP-3



#### TO252-3



# Notice

#### Precaution on using ROHM Products

1. Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment <sup>(Note 1)</sup>, transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

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CLASSⅢ		CLASS II b		
CLASSⅣ	CLASSⅢ	CLASSⅢ	CLASSⅢ	

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
  - [a] Installation of protection circuits or other protective devices to improve system safety
  - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
  - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [C] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

#### **Precautions Regarding Application Examples and External Circuits**

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### **Precaution for Storage / Transportation**

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

#### **Precaution for Product Label**

QR code printed on ROHM Products label is for ROHM's internal use only.

#### Precaution for Disposition

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